Appendix B Electrical characteristics

Absolute maximum ratings: (16F818/9)

Absolute maximum ratings: (16F818/9)	
Ambient temperature	-55° C to $+125^{\circ}$ C
Storage temperature	-65°C to $+150^{\circ}\text{C}$
Voltage on any pin with respect to Vss	
(except Vdd and MCLR)	-0.6V to Vdd $+0.6V$
Voltage on Vdd with respect to Vss	0 to $+7.5$ V
Voltage on MCLR with respect to Vss	0 to +14V
Total power dissipation	1W
Max. current out of Vss pin	200mA
Max. current into Vdd pin (16C54)	50mA
Max. current into Vdd pin	200mA
Max. output current sunk by any I/O pin	25mA
Max. output current sourced by any I/O pin	25mA
Max. output current sourced by PORTA	100mA
Max. output current sourced by PORTB	100mA
Max. output current sunk by PORTA	100mA
Max. output current sunk by PORTB	100mA

DC Characteristics.

PIC12F629/675

Characteristic	Symbol	Min.	Тур.	Max.	Units	Conditions.
Supply Voltage	Vdd					Fosc = DC to 4MHz
		2.0		5.5	V	With A/D off
		2.2		5.5	V	PIC12F675 withA/D on
		3.0		5.5	V	Fosc = 4 to 10MHz
RAM dataretention voltage	Vdr	1.5			V	Device in Sleep Mode
Supply Current	Idd		0.4	2	mA	Fosc = 4MHz, Vdd = 2V
			0.9	4	mA	Fosc = 4MHz, Vdd = 5.5V
			5.2	15	mA	Fosc = 20MHz, Vdd = 5.5V
			20	48	μΑ	Fosc = 32KHz, Vdd = 2V,
					·	WDT disabled.
Power down Current	Ipd		1	18	μΑ	Vdd = 2.0V, A/Don
(sleep mode)			0.9		μA	Vdd = 2.0V, WDT disabled

PIC16F818/9

Characteristic	Symbol	Min.	Тур.	Max.	Units	Conditions.
SupplyVoltage	Vdd	2.0		5.5	V	HS, XT, RC and LP osc modes
RAM dataretention voltage	Vdr	1.5			V	Device in Sleep Mode
Supply Current	Idd		28		μΑ	Fosc = $32KHz$, $Vdd = 5.0V$
			874		μA	Fosc = $4MHz$, $Vdd = 5.0V$
Power down Current (sleep)	Ipd		0.5		μΑ	Vdd = 5.0V

PIC16F84

Characteristic	Symbol	Min.	Typ.	Max.	Units	Conditions.
Supply Voltage	Vdd					
PIC16F84-XT		4.0		6.0	V	
PIC16F84-RC		4.0		6.0	V	
PIC16F84-HS		4.5		5.5	V	
PIC16F84-LP		4.0		6.0	V	
RAM dataretention voltage	Vdr	1.5			V	Device in Sleep Mode
Supply Current	Idd					
PIC16F84-XT			7.3	10	mA	Fosc = 4MHz, Vdd = 5.5V
PIC16F84-RC			7.3	10	mA	Fosc = 4MHz, Vdd = 5.5V
PIC16F84-HS			5	10	mA	Fosc = 10MHz, Vdd = 5.5V
PIC16F84-LP			35	400	μΑ	Fosc = 32KHz, Vdd = 3.0V,
						WDT disabled.
Power down Current	Ipd		40	100	μA	Vdd = 4.0V, WDT enabled
(sleep mode)			38	100	μA	Vdd = 4.0V, WDT disabled

PIC16F87X

1101010/11						
Characteristic	Symbol	Min.	Тур.	Max.	Units	Conditions.
Supply Voltage	Vdd	4.0		5.5	V	LP, XT, RC osc configuration
		4.5		5.5	V	HS osc configuration
RAM dataretention voltage	Vdr	1.5			V	Device in Sleep Mode
Supply Current	Idd		1.6	4	mA	Fosc = $4MHz$, $Vdd = 5.5V$
			7	15	mA	Fosc = $20MHz$, $Vdd = 5.5V$
			20	35	μΑ	Fosc = 32KHz, $Vdd = 3.0V$,
						WDT disabled.
Power down Current (sleep)	Ipd		1.5	19	μΑ	Vdd = 4.0V, WDT enabled